

### Vishay High Power Products

# Phase Control Thyristors (Hockey PUK Version), 960 A



TO-200AB (E-PUK)

<b>FEATURES</b>
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- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)



- Extended temperature range
- Low profile hockey PUK to increase current-carrying capability
- Lead (Pb)-free
- Designed and qualified for industrial level

PRODUCT SUMMARY				
I <sub>T(AV)</sub>	960 A			

#### **TYPICAL APPLICATIONS**

- · DC motor controls
- Controlled DC power supplies
- · AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		960	А			
I <sub>T(AV)</sub>	T <sub>hs</sub>	80	°C			
1		2220	А			
I <sub>T(RMS)</sub>	T <sub>hs</sub>	25	°C			
I <sub>TSM</sub>	50 Hz	12 500	٨			
	60 Hz	13 000	Α			
I <sup>2</sup> t	50 Hz	782	kA <sup>2</sup> s			
1-1	60 Hz	713	KA-S			
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 600	V			
tq	Typical	100	μs			
T <sub>J</sub>		- 40 to 150	°C			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS										
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA						
ST380CHC	04	400	500	100						
010000110	06	600	700	100						

Document Number: 94411 Revision: 11-Aug-08

## ST380CHPbF Series

## Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 960 A



ABSOLUTE MAXIMUM RATIN	GS						
PARAMETER	SYMBOL		TEST CONDITIONS				
Maximum average on-state current		180° condu	ction, half sine v	vave	960 (440)	Α	
at heatsink temperature	I <sub>T(AV)</sub>	double side	(single side) co	oled	80 (110)	°C	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 25 °C	heatsink tempe	erature double side cooled	2220		
		t = 10 ms	No voltage		12 500		
Maximum peak, one-cycle		t = 8.3 ms	reapplied		13 000	А	
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal half wave, initial $T_J = T_J$ maximum	10 500		
		t = 8.3 ms	reapplied		11 000	]	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	No voltage		782	- kA <sup>2</sup> s	
		t = 8.3 ms	reapplied		713		
		t = 10 ms	100 % V <sub>RRM</sub>		553		
		t = 8.3 ms	reapplied		505		
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10	ms, no voltage	reapplied	7820	kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$			V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(A)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			ľ	
Low level value of on-state slope resistance	r <sub>t1</sub>	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$			0.25	<b>m</b> 0	
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.24	mΩ	
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 2900 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.58	V	
Maximum holding current	I <sub>H</sub>	T 05 00 and a cold 40 V and a cold and 600			600	mA	
Typical latching current	ΙL	$T_J = 25$ °C, anode supply 12 V resistive load 1000			1000	] "	

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ $V_{DRM}$	1000	A/µs			
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1$ A/ $\mu$ s $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	1.0				
Typical turn-off time	tq	$I_{TM} = 550 \text{ A, } T_J = T_J \text{ maximum, dI/dt} = 40 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V 100 }\Omega\text{, }t_p = 500 \mu\text{s}$	100	μs			

BLOCKING							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS			
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$	500	V/µs			
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	100	mA			

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TRIGGERING						
DADAMETED	CVMPOL	TEGT COMPITIONS			VALUES	
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS		ST CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10.0		w
Maximum average gate power	$P_{G(AV)}$	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	3	.0	Α
Maximum peak positive gate voltage	+ V <sub>GM</sub>	T - T maximum	+ < 5 mg	20		V
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms			.0	<u> </u>
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest	200	-	
DC gate current required to trigger		T <sub>J</sub> = 25 °C		100	200	mA
		T <sub>J</sub> = 150 °C		40	-	
		T <sub>J</sub> = - 40 °C	value which will trigger all units	2.5	-	
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 150 °C		1.0	-	
DC gate current not to trigger	I <sub>GD</sub>	T. – T. mavimum	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any	10		mA
DC gate voltage not to trigger	$V_{GD}$	$T_J = T_J \text{ maximum}$	unit with rated V <sub>DRM</sub> anode to cathode applied	0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	TJ		- 40 to 150	°C		
Maximum storage temperature range	T <sub>Stg</sub>					
Maximum thermal registeres investigates to be stainly	Б	DC operation single side cooled	0.09			
Maximum thermal resistance, junction to heatsink	R <sub>thJ-hs</sub>	DC operation double side cooled	0.04	K/W		
Markey and the second and the second and the second and	R <sub>thC-hs</sub>	DC operation single side cooled	0.02			
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.01			
Mounting force, ± 10 %			9800 (1000)	N (kg)		
Approximate weight			83	g		
Case style		See dimensions - link at the end of datasheet	TO-200AB (E	E-PUK)		

△R <sub>thJ-hs</sub> CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR	R CONDUCTION	TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS	
180°	0.010	0.011	0.007	0.007	T <sub>J</sub> = T <sub>J</sub> maximum		
120°	0.012	0.012	0.012	0.013			
90°	0.015	0.015	0.016	0.017		K/W	
60°	0.022	0.022	0.023	0.023			
30°	0.036	0.036	0.036	0.037			

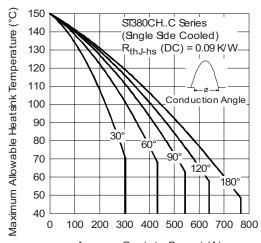
### Note

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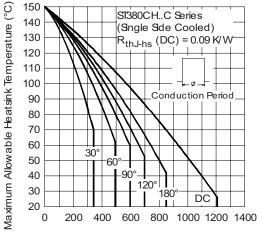
<sup>•</sup> The table above shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC

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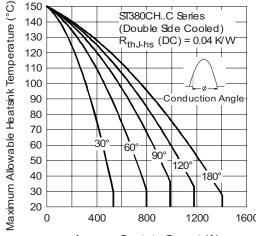




Average On-state Current (A)
Fig. 1 - Current Ratings Characteristics



Average On-state Current (A)
Fig. 2 - Current Ratings Characteristics



Average On-state Current (A)
Fig. 3 - Current Ratings Characteristics

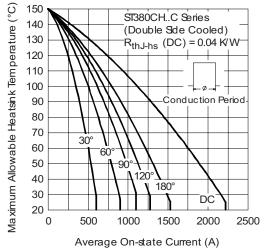
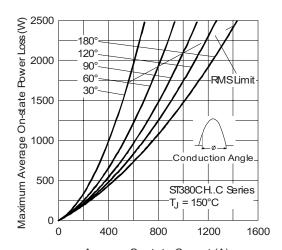


Fig. 4 - Current Ratings Characteristics



Average On-state Current (A) Fig. 5 - On-State Power Loss Characteristics

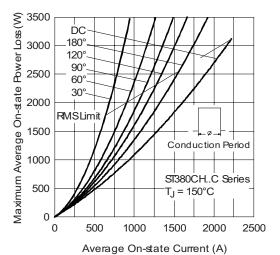


Fig. 6 - On-State Power Loss Characteristics



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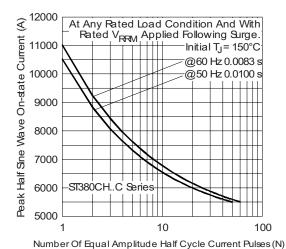


Fig. 7 - Maximum Non-Repetitive Surge Current

Single and Double Side Cooled

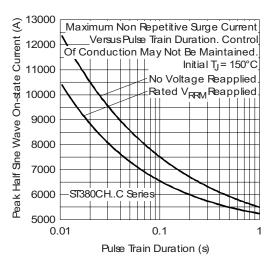


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

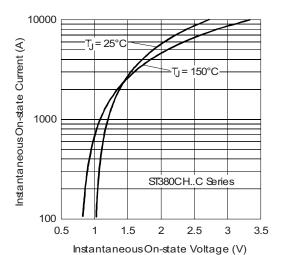


Fig. 9 - On-State Voltage Drop Characteristics

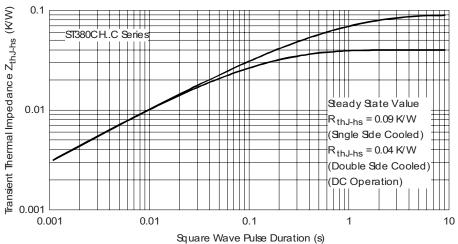


Fig. 10 - Thermal Impedance Z<sub>thJ-hs</sub> Characteristics

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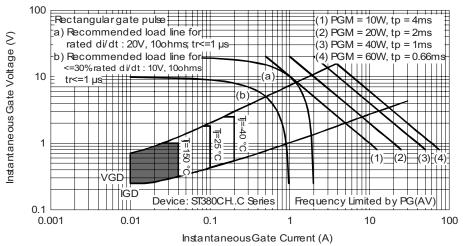
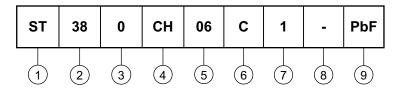


Fig. 11 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



- 1 Thyristor
- 2 Essential part number
- 3 0 = Converter grade
- 4 CH = Ceramic PUK, high temperature
- 5 Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)
- 6 C = PUK case TO-200AB (E-PUK)
- 7 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)
  - 1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)
  - 2 = Eyelet terminals (gate and auxiliary cathode soldered leads)
  - 3 = Fast-on terminals (gate and auxiliary cathode soldered leads)
- 8 Critical dV/dt: None = 500 V/µs (standard selection)
  - L = 1000 V/μs (special selection)
- 9 Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95075			



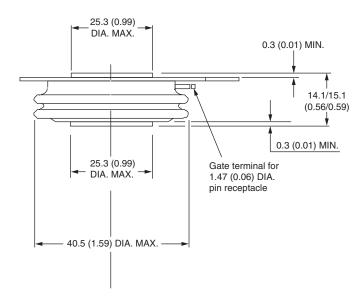
### Vishay Semiconductors

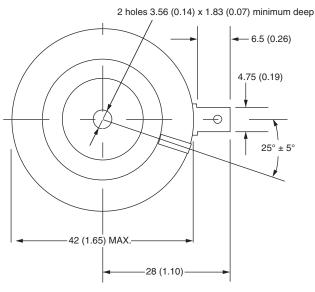
## **TO-200AB (E-PUK)**

### **DIMENSIONS** in millimeters (inches)

Anode to gate

Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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